NSN 5962-01-449-0676

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating: 1.04 watts Operating Tempurature Range: -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius	
Operating Tempurature Range: -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius	
-55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius	
Storage Tempurature Range: -65.0/+150.0 degrees celsius	
-65.0/+150.0 degrees celsius	
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End Application:	
Terminal, radio communications sets (milstar) an/frc-181 (v) and an/arc-208 (v)	
Features Provided:	
Bipolar and burn in and 3-state output and monolithic	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.0 volts input	
Time Rating Per Chacteristic:	
55.00 nanoseconds propagation delay time, low to high level output and 55.00 nanoseconds propagation delay time, high to low level output and 55.00 nanoseconds.	/el
output	
Memory Device Type:	
Pal	
Test Data Document:	
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).	
Terminal Type And Quantity:	
24 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	